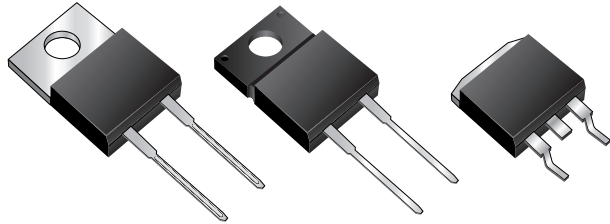




FES8JT, FESF8JT, FESB8JT Series

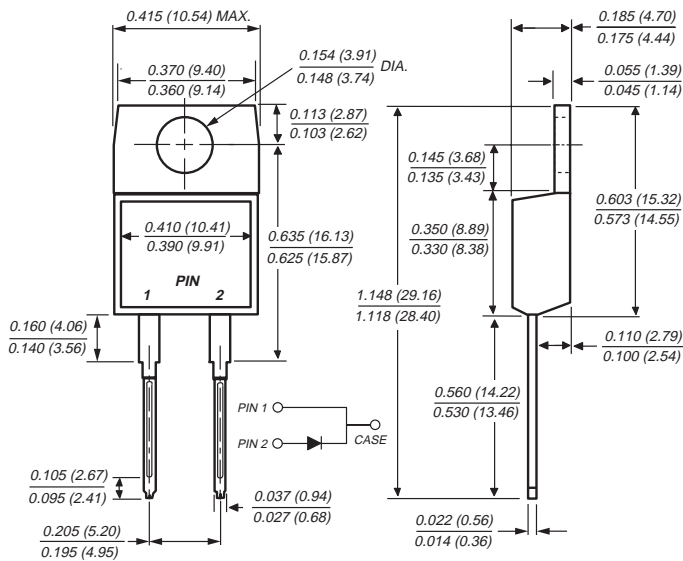
Vishay Semiconductors
formerly General Semiconductor

Ultrafast Plastic Rectifiers

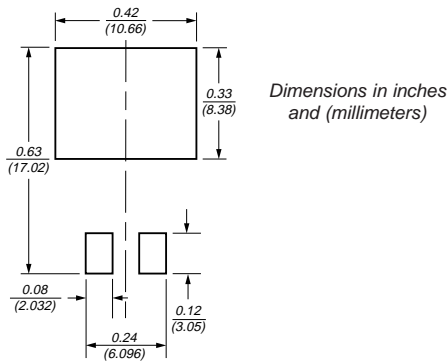


Reverse Voltage 50 to 600V
Forward Current 8.0 A
Reverse Recovery Time 35 to 50ns

TO-220AC (FES8JT)

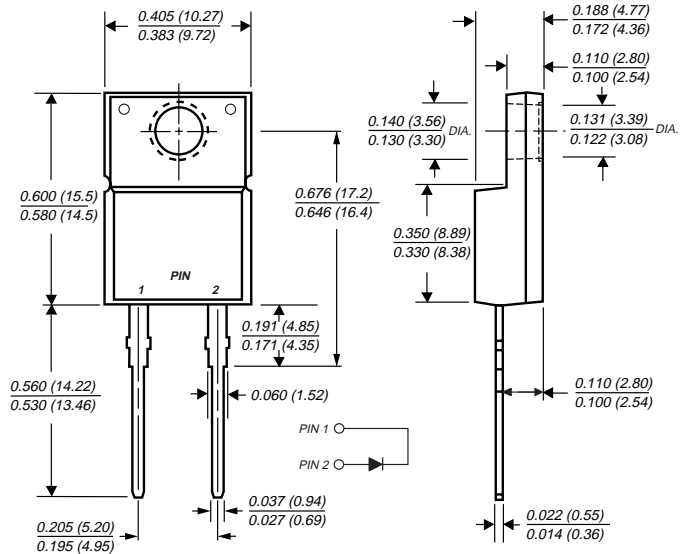


Mounting Pad Layout TO-263AB

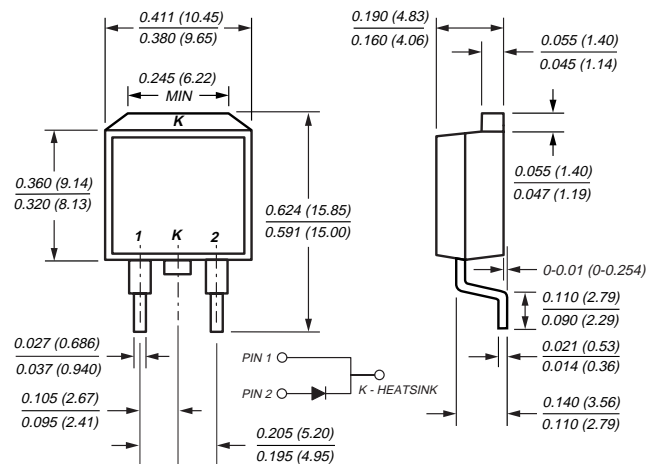


Dimensions in inches and millimeters

ITO-220AC (FESF8JT)



TO-263AB (FESB8JT)



Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated chip junction
- Low leakage, high voltage
- High surge current capability
- Superfast recovery time, for high efficiency

Mechanical Data

Case: JEDEC TO-220AC, ITO-220AC & TO-263AB molded plastic body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

High temperature soldering guaranteed: 250°C, 0.16" (4.06mm) from case for 10 seconds

Polarity: As marked **Mounting Position:** Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08 oz., 2.24 g

FES8JT, FESF8JT, FESB8JT Series

Vishay Semiconductors
formerly General Semiconductor



Maximum Ratings Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	FES 8AT	FES 8BT	FES 8CT	FES 8DT	FES 8FT	FES 8GT	FES 8HT	FES 8JT	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current at T _C =100°C	I _{F(AV)}	8.0								A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at T _C =100°C	I _{FSM}	200				125				A
Operating storage and temperature range	T _J , T _{STG}	-55 to +150								°C
RMS Isolation voltage (FESF type only) from terminals to heatsink with t=1.0 second, RH≤30%	V _{ISOL}	4500 ⁽¹⁾ 3500 ⁽²⁾ 1500 ⁽³⁾								V

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	FES 8AT	FES 8BT	FES 8CT	FES 8DT	FES 8FT	FES 8GT	FES 8HT	FES 8JT	Unit
Maximum instantaneous forward voltage @ 8.0A ⁽⁴⁾	V _F	0.95				1.30		1.50		V
Maximum DC reverse current at rated DC blocking voltage T _C =25°C T _C =100°C	I _R	10 500								μA
Maximum reverse recovery time at I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	t _{rr}	35				50				ns
Typical junction capacitance at 4V, 1MHz	C _J	85						50		pF

Thermal Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	FES	FESF	FESB	Unit
Typical thermal resistance from junction to case	R _{θJC}	2.2	5.0	2.2	°C/W

Notes:

- (1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
- (2) Clip mounting (on case), where leads do overlap heatsink
- (3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
- (4) Pulse test: 300μs pulse width, 1% duty cycle

Ordering Information

Product	Case	Package Code	Package Option
FES8AT thru FES8JT	TO-220AC	45	Anti-Static tube, 50/tube, 2K/carton
FESF8AT thru FESF8JT	ITO-220AC	45	Anti-Static tube, 50/tube, 2K/carton
FESB8AT thru FESB8JT	TO-263AB	31 45 81	13" reel, 800/reel, 4.8K/carton Anti-Static tube, 50/tube, 2K/carton Anti-Static 13" reel, 800/reel, 4.8K/carton

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Maximum Forward Current Derating Curve

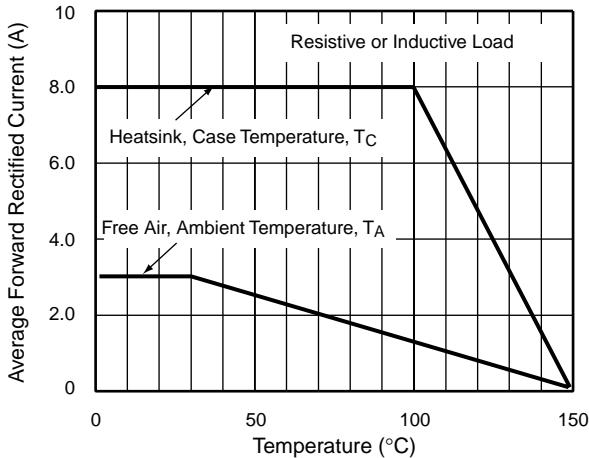


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

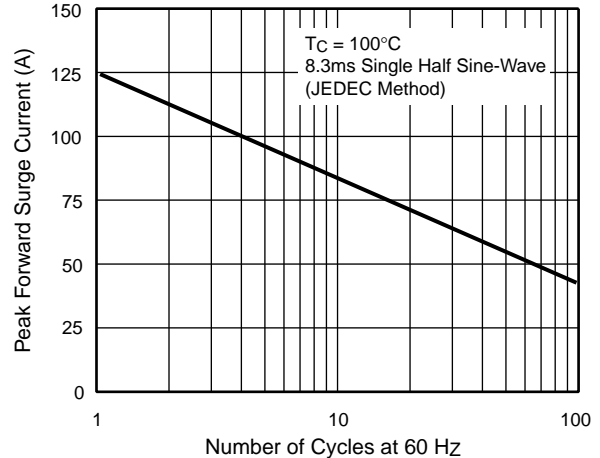


Fig. 3 – Typical Instantaneous Forward Characteristics

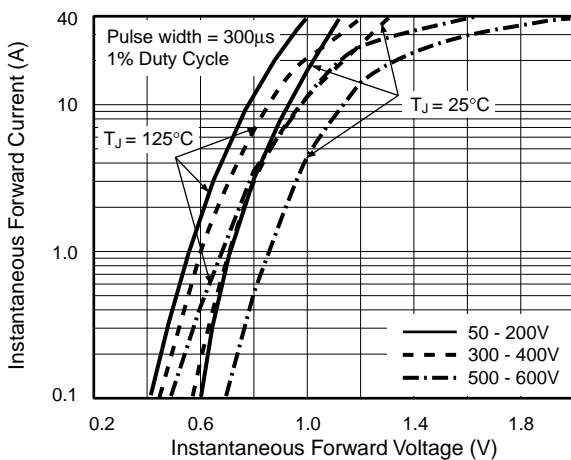


Fig. 4 – Typical Reverse Leakage Characteristics

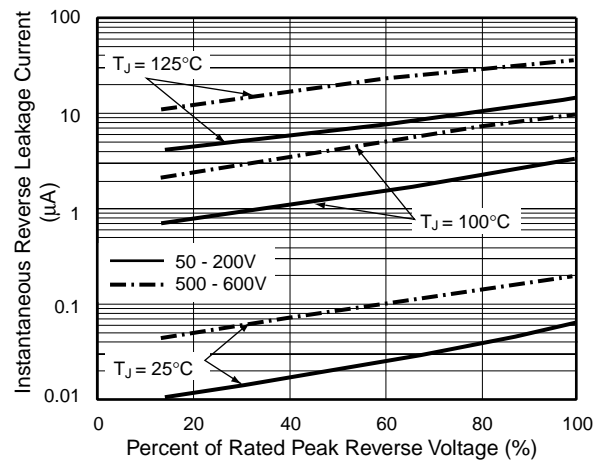
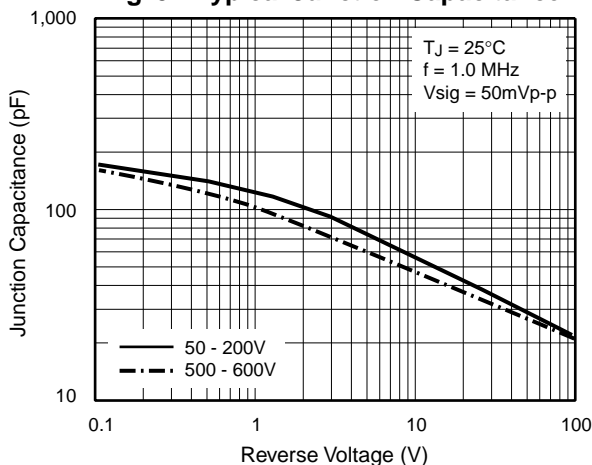


Fig. 5 – Typical Junction Capacitance



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